

FS5UMH-2

HIGH-SPEED SWITCHING USE

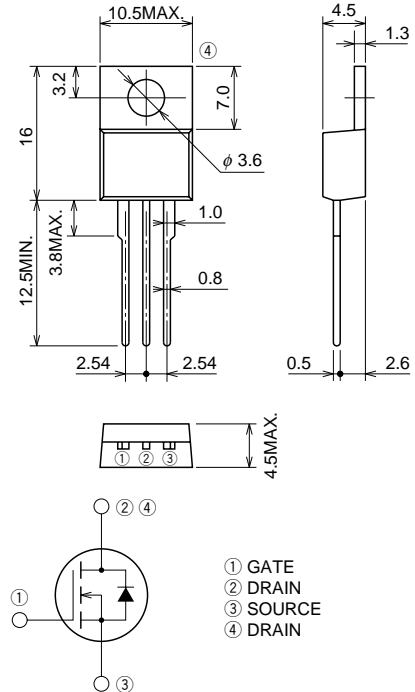
FS5UMH-2



- 2.5V DRIVE
- V_{DSS} 100V
- r_{DS (ON)} (MAX) 0.44Ω
- I_D 5A
- Integrated Fast Recovery Diode (TYP.) 80ns

OUTLINE DRAWING

Dimensions in mm



TO-220

APPLICATION

Motor control, Lamp control, Solenoid control
DC-DC converter, etc.

MAXIMUM RATINGS (T_c = 25°C)

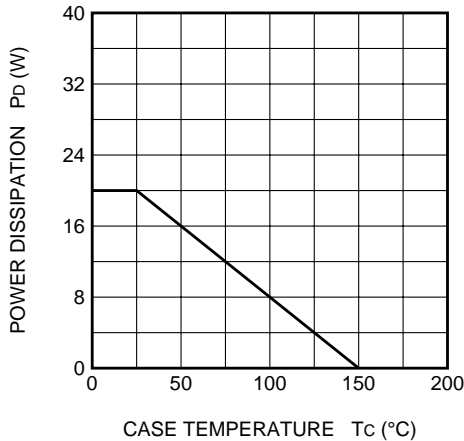
| Symbol | Parameter | Conditions | Ratings | Unit |
|------------------|----------------------------------|----------------------|------------|------|
| V _{DSS} | Drain-source voltage | V _{GS} = 0V | 100 | V |
| V _{GSS} | Gate-source voltage | V _{DS} = 0V | ±10 | V |
| I _D | Drain current | | 5 | A |
| I _{DM} | Drain current (Pulsed) | | 20 | A |
| I _{DA} | Avalanche drain current (Pulsed) | L = 100μH | 5 | A |
| I _S | Source current | | 5 | A |
| I _{SM} | Source current (Pulsed) | | 20 | A |
| P _D | Maximum power dissipation | | 20 | W |
| T _{ch} | Channel temperature | | -55 ~ +150 | °C |
| T _{stg} | Storage temperature | | -55 ~ +150 | °C |
| — | Weight | Typical value | 2.0 | g |

ELECTRICAL CHARACTERISTICS (Tch = 25°C)

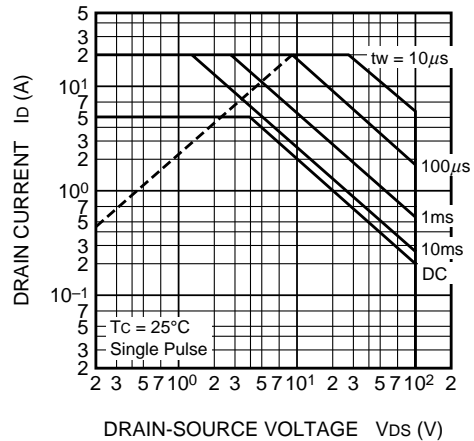
| Symbol | Parameter | Test conditions | Limits | | | Unit |
|-----------|----------------------------------|------------------------------------------------|--------|------|------|------|
| | | | Min. | Typ. | Max. | |
| V(BR)DSS | Drain-source breakdown voltage | ID = 1mA, VGS = 0V | 100 | — | — | V |
| IGSS | Gate-source leakage current | VGS = ±10V, VDS = 0V | — | — | ±0.1 | μA |
| IDSS | Drain-source leakage current | VDS = 100V, VGS = 0V | — | — | 0.1 | mA |
| VGS(th) | Gate-source threshold voltage | ID = 1mA, VDS = 10V | 0.6 | 0.9 | 1.2 | V |
| rDS(ON) | Drain-source on-state resistance | ID = 2A, VGS = 4V | — | 0.32 | 0.44 | Ω |
| rDS(ON) | Drain-source on-state resistance | ID = 2A, VGS = 2.5V | — | 0.34 | 0.47 | Ω |
| VDS(ON) | Drain-source on-state voltage | ID = 2A, VGS = 4V | — | 0.64 | 0.88 | V |
| yfs | Forward transfer admittance | ID = 2A, VDS = 5V | — | 10 | — | S |
| Ciss | Input capacitance | VDS = 10V, VGS = 0V, f = 1MHz | — | 540 | — | pF |
| Coss | Output capacitance | | — | 75 | — | pF |
| Crss | Reverse transfer capacitance | | — | 20 | — | pF |
| td(on) | Turn-on delay time | VDD = 50V, ID = 2A, VGS = 4V, RGEN = RGS = 50Ω | — | 12 | — | ns |
| tr | Rise time | | — | 18 | — | ns |
| td(off) | Turn-off delay time | | — | 45 | — | ns |
| tf | Fall time | | — | 26 | — | ns |
| VSD | Source-drain voltage | IS = 2A, VGS = 0V | — | 1.0 | 1.5 | V |
| Rth(ch-c) | Thermal resistance | Channel to case | — | — | 6.25 | °C/W |
| trr | Reverse recovery time | IS = 5A, dis/dt = -100A/μs | — | 80 | — | ns |

PERFORMANCE CURVES

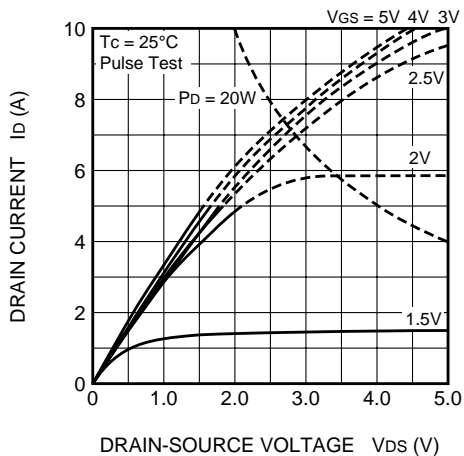
POWER DISSIPATION DERATING CURVE



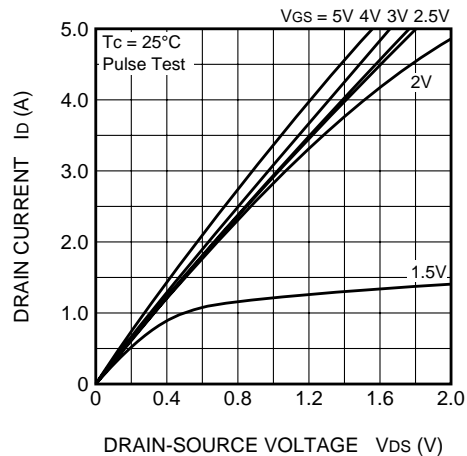
MAXIMUM SAFE OPERATING AREA



OUTPUT CHARACTERISTICS (TYPICAL)



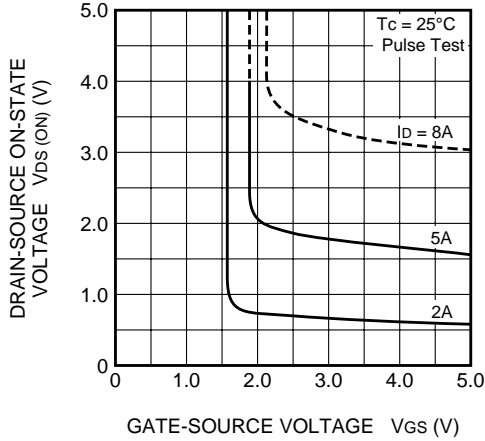
OUTPUT CHARACTERISTICS (TYPICAL)



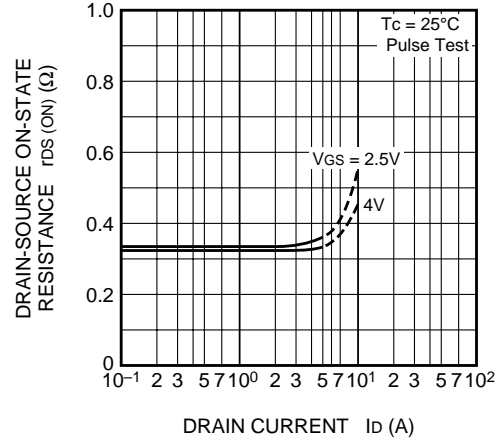
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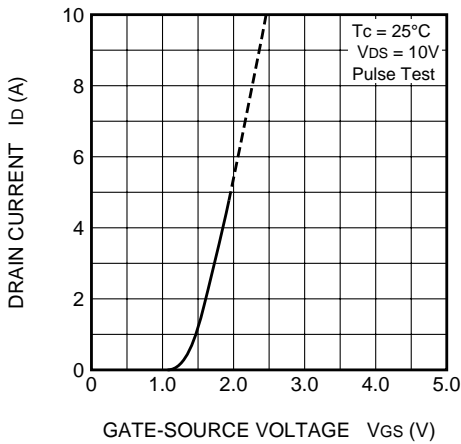
ON-STATE VOLTAGE VS. GATE-SOURCE VOLTAGE (TYPICAL)



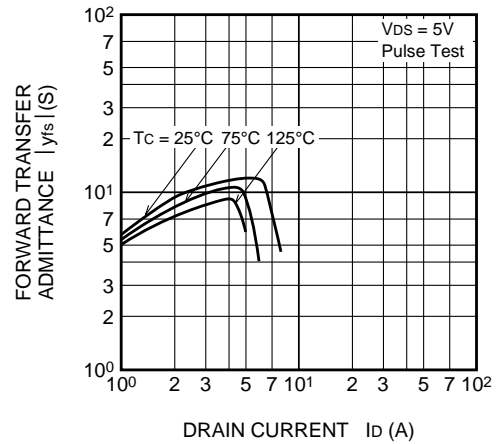
ON-STATE RESISTANCE VS. DRAIN CURRENT (TYPICAL)



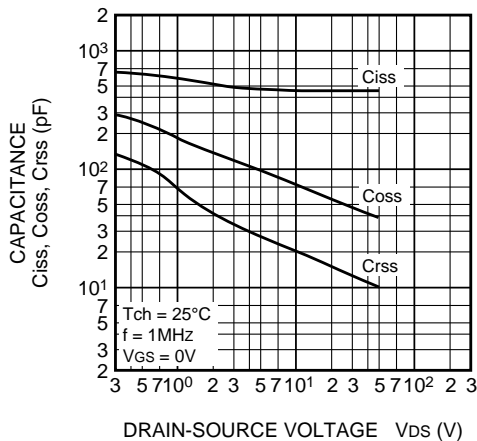
TRANSFER CHARACTERISTICS (TYPICAL)



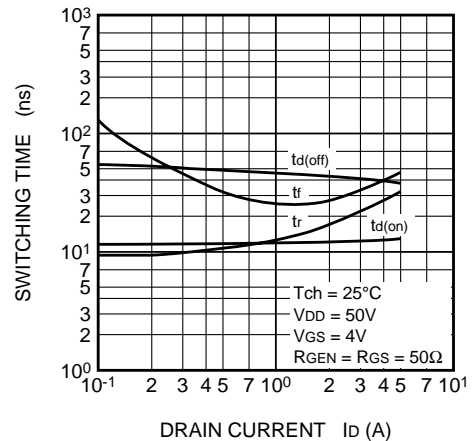
FORWARD TRANSFER ADMITTANCE VS. DRAIN CURRENT (TYPICAL)



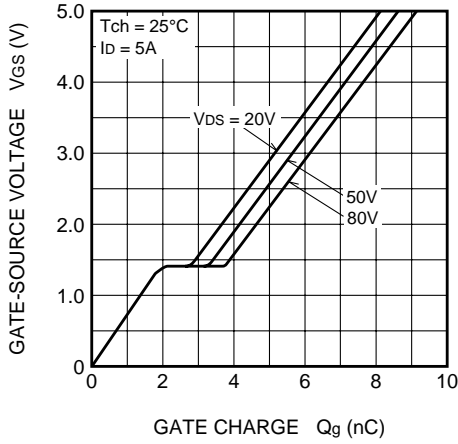
CAPACITANCE VS. DRAIN-SOURCE VOLTAGE (TYPICAL)



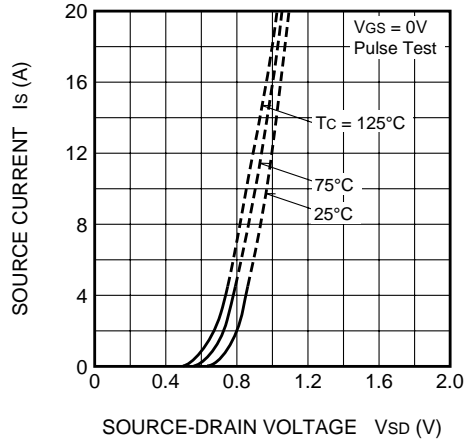
SWITCHING CHARACTERISTICS (TYPICAL)



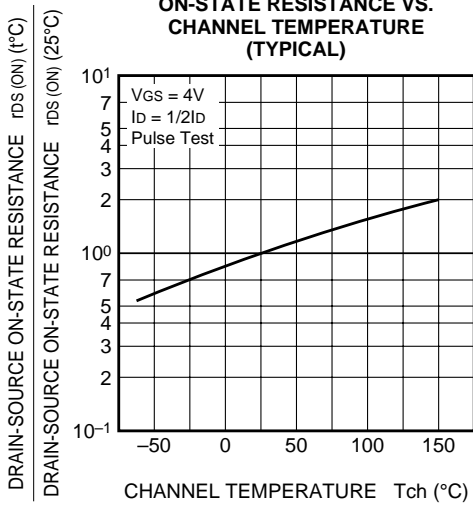
GATE-SOURCE VOLTAGE VS. GATE CHARGE (TYPICAL)



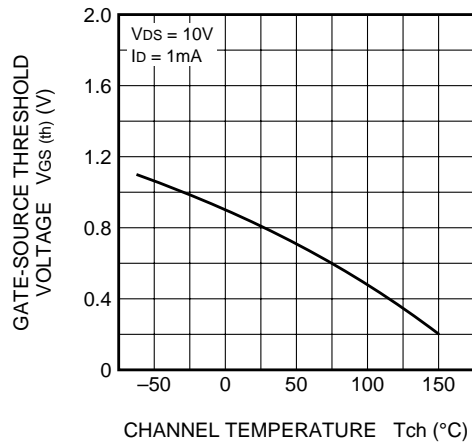
SOURCE-DRAIN DIODE FORWARD CHARACTERISTICS (TYPICAL)



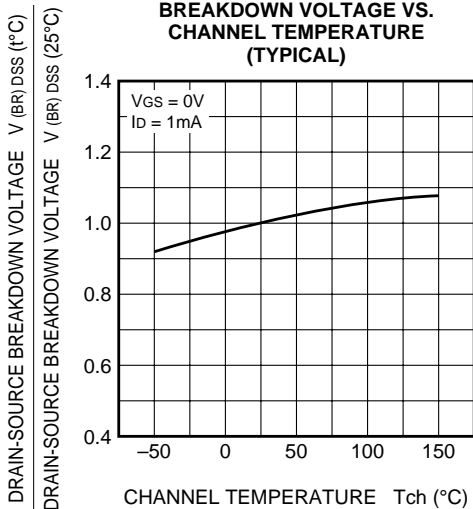
ON-STATE RESISTANCE VS. CHANNEL TEMPERATURE (TYPICAL)



THRESHOLD VOLTAGE VS. CHANNEL TEMPERATURE (TYPICAL)



BREAKDOWN VOLTAGE VS. CHANNEL TEMPERATURE (TYPICAL)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS

